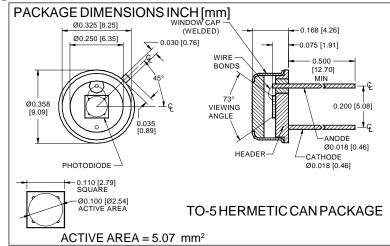
PHOTONICSilicon Photodiode, Blue Enhanced Photoconductive **DETECTORS INC.**Type PDB-C115





FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current

DESCRIPTION

The **PDB-C115** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-5 metal can with a flat window.

APPLICATIONS

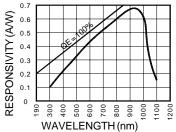
- Instrumentation
- Oximeters
- Lasersensor
- Medical sensor

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	
V _{BR}	Reverse Voltage		100	V	
T _{STG}	Storage Temperature	-55	+150	∘C	
То	Operating Temperature Range	-40	+125	∘C	
Ts	Soldering Temperature*		+240	∘C	
I	Light Current		1.0	mA	

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	45	65		μ A
ΙD	Dark Current	$H = 0, V_R = 10 V$		1.0	5.0	nA
Rsн	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$.5	2		GΩ
TC Rsh	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/℃
Сı	Junction Capacitance	H = 0, V _R = 10 V**		15		pF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
V _{BR}	Breakdown Voltage	I = 10 μA	100	125		V
NEP	Noise Equivalent Power	VR = 10 V @ Peak		2.5x10 ⁻¹⁴		W/ √Hz
tr	Response Time	$RL = 1 K\Omega V_R = 50 V$		15		nS